

TECHNICAL DATA
DATA SHEET 181, REV. C.1
Formerly SHD3166/B

HERMETIC POWER ULTRAFAST RECTIFIER

DESCRIPTION: A 200 VOLT, 25 AMP, HERMETIC POWER ULTRAFAST RECTIFIER IN A SHD-1/1B PACKAGE.

MAXIMUM RATINGS

All ratings are @ $T_A = 25^\circ\text{C}$ unless otherwise specified

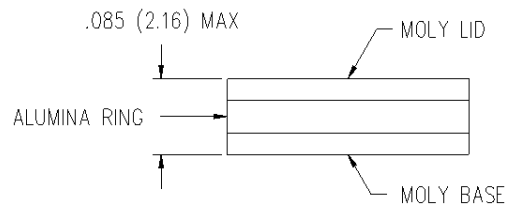
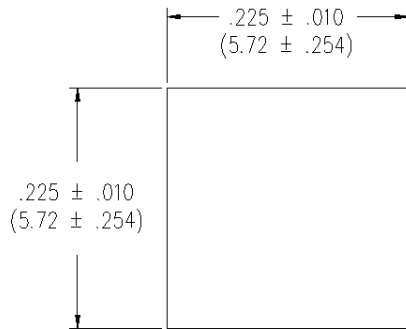
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	200	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_o	25	Amps
MAXIMUM REVERSE RECOVERY TIME ($I_f = 0.5\text{A}$, $I_r = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$)	t_{rr}	35	nsec
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R\theta_{JC}$	1.3	$^\circ\text{C}/\text{W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-55 to +175	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

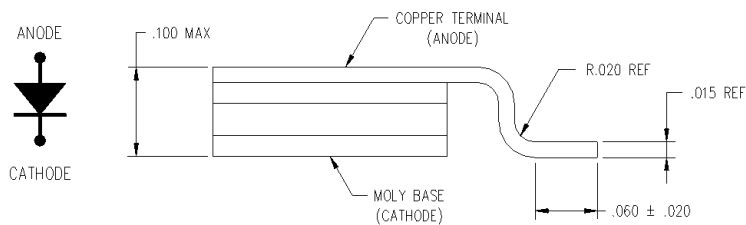
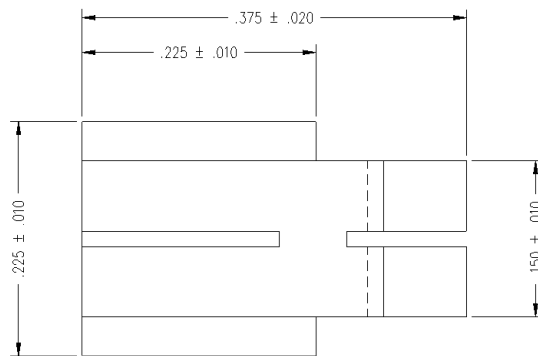
CHARACTERISTIC				
MAXIMUM FORWARD VOLTAGE DROP, Pulsed	$T_C = 25^\circ\text{C}$ ($I_f = 25\text{Amps}$)	V_f	.975	Volts
MAXIMUM FORWARD VOLTAGE DROP, Pulsed	$T_C = 125^\circ\text{C}$ ($I_f = 25\text{Amps}$)	V_f	.875	Volts
MAXIMUM REVERSE CURRENT	$T_C = 25^\circ\text{C}$ I_r @ 200 PIV	I_r	25	μA
MAXIMUM REVERSE CURRENT	$T_C = 125^\circ\text{C}$ I_r @ 200 PIV	I_r	1.0	mA

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MECHANICAL DIMENSIONS: In Inches / mm



SHD-1



SHD-1B

SENSITRON
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PART ORDERING INFORMATION:

SHD316311BXX X

↓
Part Number

Screening Level (blank is no screening):

Suffix	Screened in Accordance with:
blank	No screening level
S	MIL-PRF-19500, TXV Level
SS	MIL-PRF-19500, S Level

QCI (blank is no QCI):

Suffix	Inspection in Accordance with:
blank	No QCI
Q	MIL-PRF-19500 QCI

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